



ZVN4206GV

SOT223 N-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET

Product Summary

| V _{(BR)DSS} | Max R _{DS(on)} | Max I _D T _A = +25°C | |
|----------------------|----------------------------|--|--|
| 60V | 1Ω @ $V_{GS} = 10V$ | 1A | |

Description and Applications

- Automotive Relay Drivers
- Stepper Motor Driver

Features and Benefits

- Repetitive avalanche rating
- No transient protection required
- Characterized for 5V logic drive
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

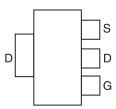
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)

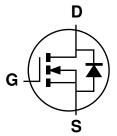




Top View



Pin Out Top-view



Equivalent Circuit

Ordering Information (Note 4)

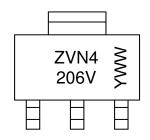
| Part Number | Compliance | Case | Packaging |
|-------------|------------|--------|-----------|
| ZVN4206GVTA | Standard | SOT223 | 1,000 |

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

SOT223



ZVN4 206V = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W$ = Week Code (01~53)



Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--------------------------------|-----------------|-------|------|
| Drain-Source Voltage | $V_{ m DSS}$ | 60 | V |
| Gate-Source Voltage | V _{GS} | ±20 | V |
| Continuous Drain Current | I _D | 1 | A |
| Pulsed Drain Current | I _{DM} | 8 | Α |
| Continuous Drain Current | I _D | 1 | A |
| Continuous Body Diode Current | I _{SD} | 600 | mA |
| Avalanche Current - Repetitive | I _{AR} | 600 | mA |
| Avalanche Energy - Repetitive | E _{AR} | 15 | mJ |

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|---|-----------------------------------|-------------|-----------------|
| Power Dissipation at T _A = +25 ℃ | P _{tot} | 2 | W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | $_{\mathbb{C}}$ |

Electrical Characteristics (@T_A = +25 °C, unless otherwise specified.)

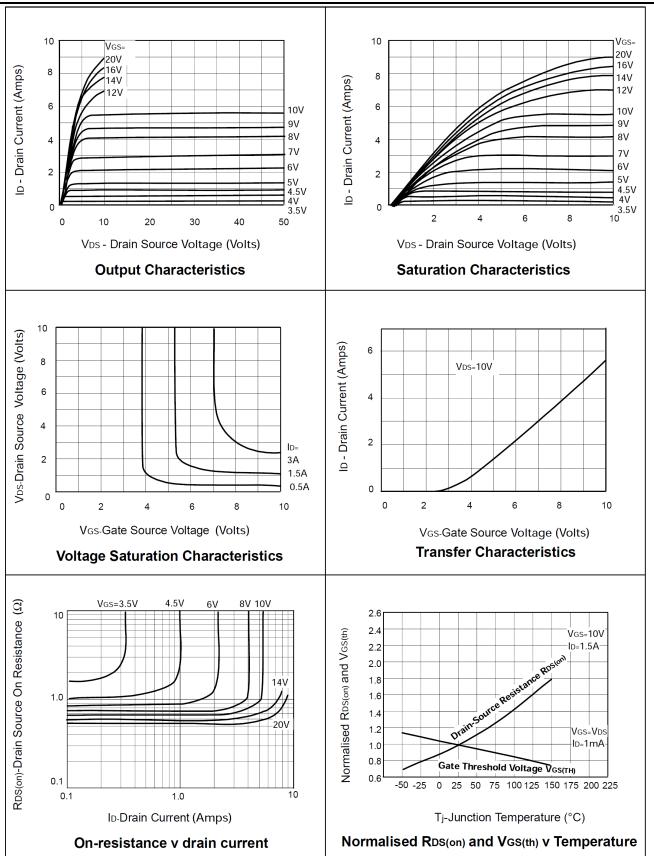
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|----------------------|-----|-----|-----|------|--|--|
| OFF CHARACTERISTICS | | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | 60 | _ | _ | V | $I_D = 1mA$, $V_{GS} = 0V$ | |
| | | | | 10 | | $V_{DS} = 60V, V_{GS} = 0V$ | |
| Zero Gate Voltage Drain Current | I _{DSS} | _ | _ | 100 | μA | $V_{DS} = 48V$, $V_{GS} = 0V$, $T=+125$ °C (Note 6) | |
| Gate-Body Leakage | I _{GSS} | _ | _ | 100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| Gate-Source Threshold Voltage | V _{GS(th)} | 1.3 | _ | 3 | V | $I_D = 1mA$, $V_{DS} = V_{GS}$ | |
| On-State Drain Current (Note 5) | $I_{D(on)}$ | 3 | _ | _ | Α | $V_{DS} = 25V, V_{GS} = 10V$ | |
| Static Drain-Source On-State Resistance (Note 5) | R _{DS} (ON) | _ | _ | 1 | Ω | $V_{GS} = 10V, I_D = 1.5A$ | |
| Static Diani-Source On-State nesistance (Note 3) | | _ | _ | 1.5 | | $V_{GS} = 5V, I_D = 0.5A$ | |
| Forward Transconductance (Notes 5 & 6) | g _{fs} | 300 | _ | _ | ms | $V_{DS} = 25V, I_D = 1.5A$ | |
| DYNAMIC CHARACTERISTICS | | | | | | | |
| Input Capacitance (Note 6) | Ciss | _ | _ | 100 | рF | V 05 V V 0V | |
| Output Capacitance (Note 6) | Coss | _ | _ | 60 | рF | V _{DS} = 25 V, V _{GS} = 0V - f = 1MHz | |
| Reverse Transfer Capacitance (Note 6) | Crss | _ | _ | 20 | рF | | |
| Turn-On Delay Time (Notes 6 & 7) | t _{d(on)} | _ | _ | 8 | ns | $V_{DD} \approx 25V$, $V_{GEN} = 10V$ $I_D = 1.5A$ | |
| Turn-On Rise Time (Notes 6 & 7) | tr | _ | _ | 12 | ns | | |
| Turn-Off Delay Time (Notes 6 & 7) | t _{d(off)} | _ | | 12 | ns | | |
| Turn-Off Fall Time (Notes 6 & 7) | t _f | _ | _ | 15 | ns | | |

5. Measured under pulsed conditions. Width=300μs. Duty cycle ≤ 2%. Notes:

^{6.} Sample test. 7. Switching times measured with 50 Ω source impedance and <5ns rise time on a pulse generator.

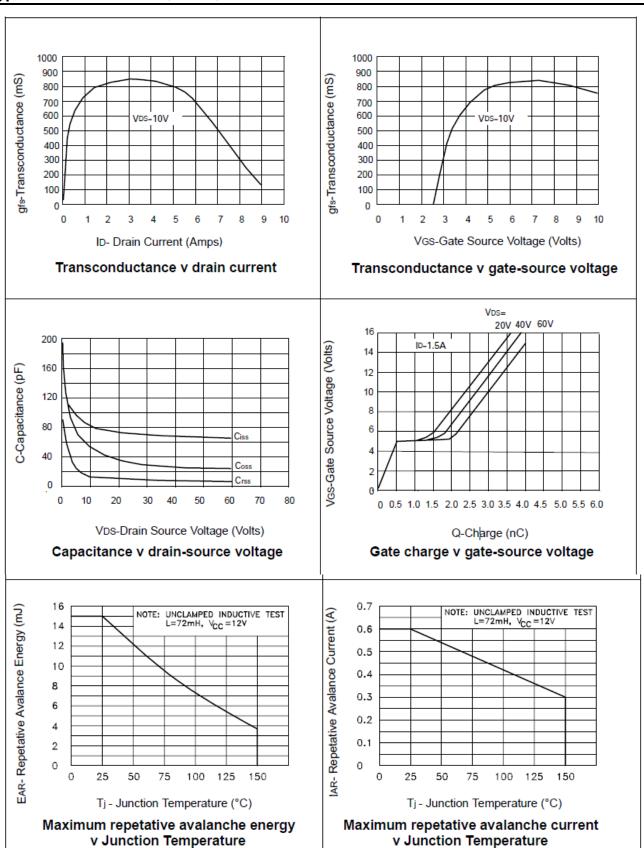


Typical Characteristics





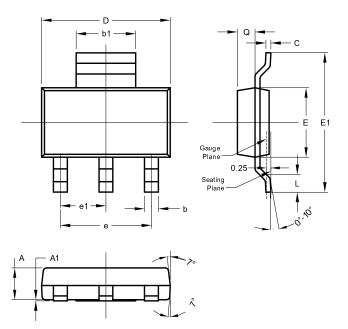
Typical Characteristics (continued)





Package Outline Dimensions

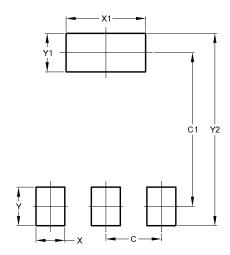
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



| SOT223 | | | | |
|----------------------|-------|------|------|--|
| Dim | Min | Max | Тур | |
| Α | 1.55 | 1.65 | 1.60 | |
| A 1 | 0.010 | 0.15 | 0.05 | |
| b | 0.60 | 0.80 | 0.70 | |
| b1 | 2.90 | 3.10 | 3.00 | |
| C | 0.20 | 0.30 | 0.25 | |
| D | 6.45 | 6.55 | 6.50 | |
| Е | 3.45 | 3.55 | 3.50 | |
| E1 | 6.90 | 7.10 | 7.00 | |
| e | - | - | 4.60 | |
| e1 | - | - | 2.30 | |
| L | 0.85 | 1.05 | 0.95 | |
| Q | 0.84 | 0.94 | 0.89 | |
| All Dimensions in mm | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| С | 2.30 |
| C1 | 6.40 |
| Х | 1.20 |
| X1 | 3.30 |
| Υ | 1.60 |
| Y1 | 1.60 |
| C2 | 8 00 |



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